BT134W series E

GENERAL DESCRIPTION

Glass passivated, sensitive gate triacs in a plastic envelope suitable for surface mounting, intended for use in general purpose bidirectional switching and phase control applications, where high sensitivity is

QUICK REFERENCE DATA

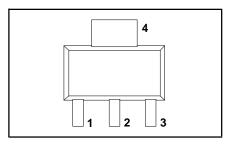
SYMBOL	PARAMETER	MAX.	MAX.	UNIT
V _{DRM} I _{T(RMS)} I _{TSM}	BT134W- Repetitive peak off-state voltages RMS on-state current Non-repetitive peak on-state current	500E 500 1 10	600E 600 1	V A A

PINNING - SOT223

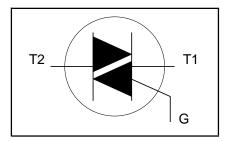
required in all four quadrants.

PIN	DESCRIPTION
1	main terminal 1
2	main terminal 2
3	gate
tab	main terminal 2

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
V_{DRM}	Repetitive peak off-state voltages		-	-500 500 ¹	-600 600 ¹	V
I _{T(RMS)}	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{sp} \le 108 ^{\circ}\text{C}$ full sine wave; $T_{j} = 25 ^{\circ}\text{C}$ prior to surge	-	1		A
		t = 20 ms	-		0	A
l ² t	I ² t for fusing	t = 16.7 ms t = 10 ms	_	11 0.5		A A ² s
dl _⊤ /dt	Repetitive rate of rise of on-state current after	$I_{TM} = 1.5 \text{ A}; I_G = 0.2 \text{ A}; \\ dI_G/dt = 0.2 \text{ A}/\mu\text{s}$.0	'
	triggering	T2+ G+	-		0	A/μs
		T2+ G-	-		0	A/μs
		T2- G- T2- G+	<u>-</u>		0 0	A/μs
I _{GM}	Peak gate current	12- 9+	_	<u>'</u>	>	A/μs A
V _{GM}	Peak gate voltage		_	Į	5	V
l P _{GM}	Peak gate power		-			W
P _{G(AV)} T _{stg} T _j	Average gate power Storage temperature Operating junction temperature	over any 20 ms period	- -40 -	15	.5 50 25	Ç Ç W

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¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 3 A/µs.

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-sp}	Thermal resistance junction to solder point	full or half cycle	-	-	15	K/W
R _{th i-a}	Thermal resistance	pcb mounted; minimum footprint pcb mounted; pad area as in fig:14	-	156 70	-	K/W K/W

STATIC CHARACTERISTICS

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}$					
			T2+ G+	-	2.5	10	mΑ
			T2+ G-	-	4.0	10	mΑ
			T2- G-	-	5.0	10	mΑ
			T2- G+	-	11	25	mΑ
I _L	Latching current	$V_D = 12 \text{ V}; I_{GT} = 0.1 \text{ A}$					
			T2+ G+	-	3.0	15	mΑ
			T2+ G-	-	10	20	mΑ
			T2- G-	-	2.5	15	mA
			T2- G+	-	4.0	20	mΑ
l I _H	Holding current	$V_D = 12 \text{ V}; I_{GT} = 0.1 \text{ A}$		-	2.2	15	mA
V _T	On-state voltage	$I_T = 2 A$		-	1.2	1.5	V
V _{GT}	Gate trigger voltage	$\begin{vmatrix} \dot{V}_D = 12 \text{ V}; I_T = 0.1 \text{ A} \\ V_D = 400 \text{ V}; I_T = 0.1 \text{ A}; T_i = 125 ^\circ$	_	-	0.7	1.5	V
		$ V_D = 400 \text{ V}; I_T = 0.1 \text{ A}; T_L = 125 ^\circ$	C C	0.25	0.4	-	V
I_D	Off-state leakage current	$V_D = V_{DRM(max)}$, $T_j = 125$ °C		-	0.1	0.5	mA

DYNAMIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$		30	-	V/μs
t _{gt}	off-state voltage Gate controlled turn-on time	exponential waveform, gate open circuit $I_{TM} = 1.5 \text{ A}$; $V_D = V_{DRM(max)}$; $I_G = 0.1 \text{ A}$; $dI_G/dt = 5 \text{ A}/\mu\text{S}$	-	2	-	μs

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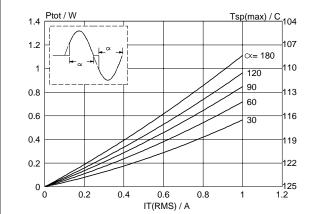


Fig.1. Maximum on-state dissipation, P_{tot} , versus rms on-state current, $I_{T(RMS)}$, where α = conduction angle.

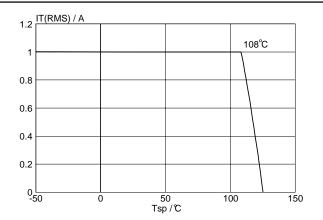


Fig.4. Maximum permissible rms current $I_{T(RMS)}$, versus solder point temperature T_{sp} .

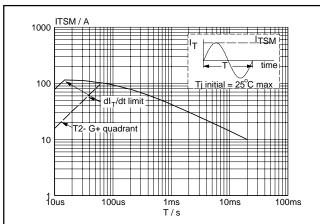


Fig.2. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus pulse width t_p , for sinusoidal currents, $t_p \le 20$ ms.

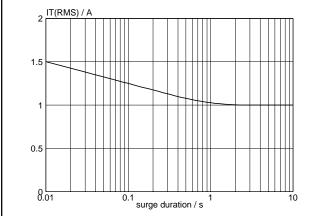


Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{sp} \le 108$ °C.

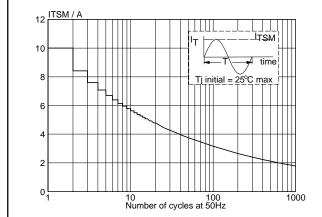


Fig.3. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus number of cycles, for sinusoidal currents, f = 50 Hz.

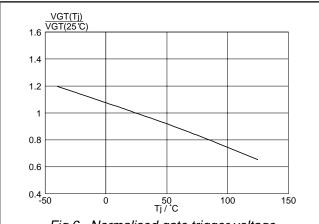
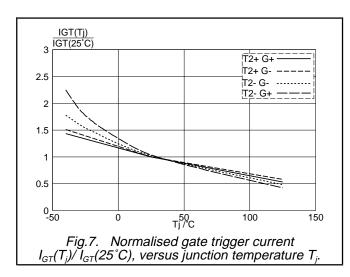
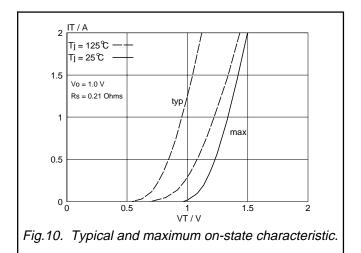
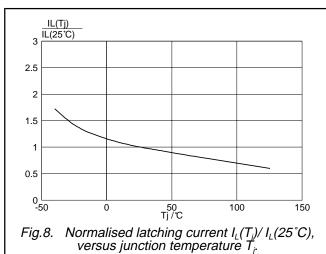


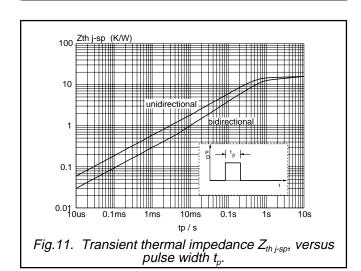
Fig.6. Normalised gate trigger voltage $V_{GT}(T_j)/V_{GT}(25\,^{\circ}C)$, versus junction temperature T_j .

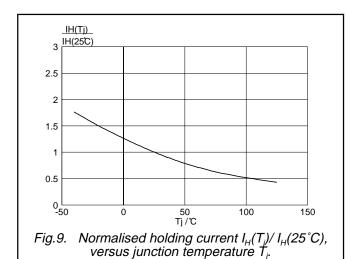
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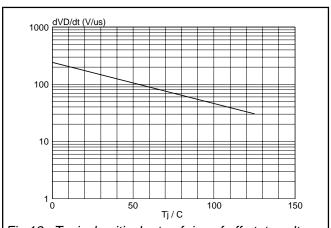
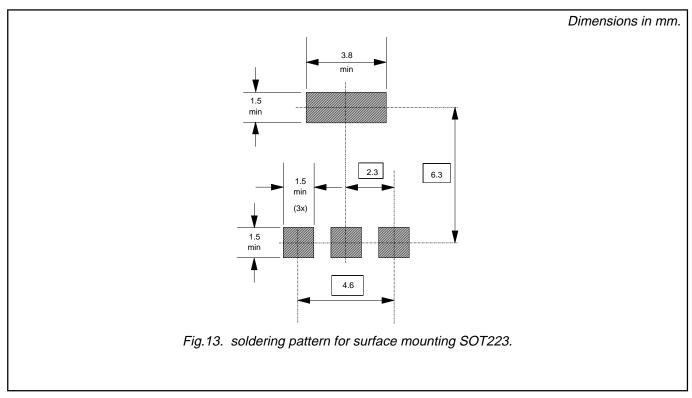


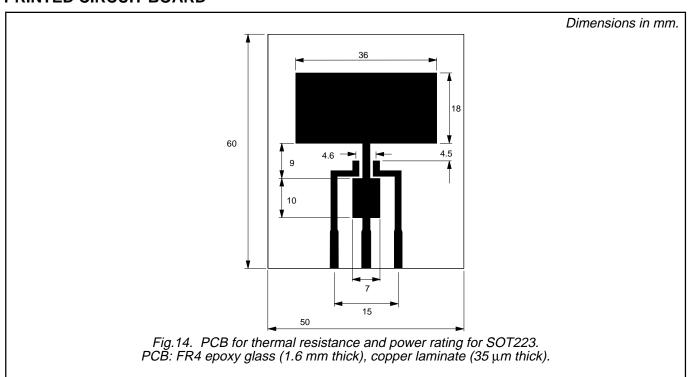
Fig.12. Typical, critical rate of rise of off-state voltage, dV_D/dt versus junction temperature T_i.

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MOUNTING INSTRUCTIONS

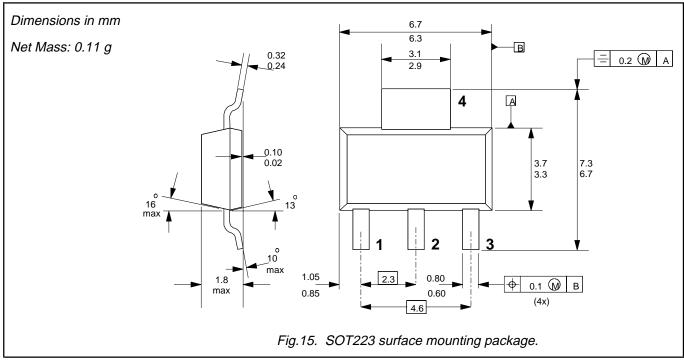


PRINTED CIRCUIT BOARD



BT134W series E

MECHANICAL DATA



Notes

- For further information, refer to Philips publication SC18 " SMD Footprint Design and Soldering Guidelines".
 Order code: 9397 750 00505.
 Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

Triacs sensitive gate

BT134W series E

DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Product specification	This data sheet contains final product specifications.				

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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